

SN54ABT823, SN74ABT823 9-BIT BUS-INTERFACE FLIP-FLOPS WITH 3-STATE OUTPUTS

SCBS158C – JANUARY 1991 – REVISED JULY 1994

- State-of-the-Art *EPIC-II^B*™ BiCMOS Design Significantly Reduces Power Dissipation
- Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17
- Typical V_{OLP} (Output Ground Bounce) < 1 V at $V_{CC} = 5$ V, $T_A = 25^\circ\text{C}$
- High-Drive Outputs ($-32\text{-mA } I_{OH}$, $64\text{-mA } I_{OL}$)
- Buffered Control Inputs to Reduce DC Loading Effects
- Package Options Include Plastic Small-Outline (DW) and Shrink Small-Outline (DB) Packages, Ceramic Chip Carriers (FK) and Flatpacks (W), and Standard Plastic (NT) and Ceramic (JT) DIPs

description

These 9-bit flip-flops feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing wider buffer registers, I/O ports, bidirectional bus drivers with parity, and working registers.

With the clock-enable ($\overline{\text{CLKEN}}$) input low, the nine D-type edge-triggered flip-flops enter data on the low-to-high transitions of the clock. Taking $\overline{\text{CLKEN}}$ high will disable the clock buffer, thus latching the outputs. The 'ABT823 has noninverting data (D) inputs. Taking the clear ($\overline{\text{CLR}}$) input low causes the nine Q outputs to go low independently of the clock.

A buffered output-enable ($\overline{\text{OE}}$) input can be used to place the nine outputs in either a normal logic state (high or low level) or a high-impedance state.

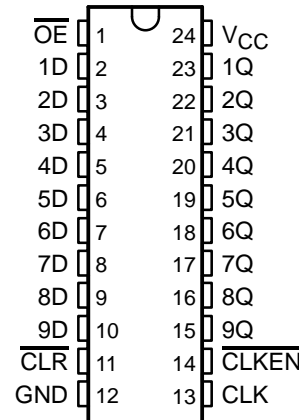
In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pullup components.

$\overline{\text{OE}}$ does not affect the internal operations of the latch. Previously stored data can be retained or new data can be entered while the outputs are in the high-impedance state. To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

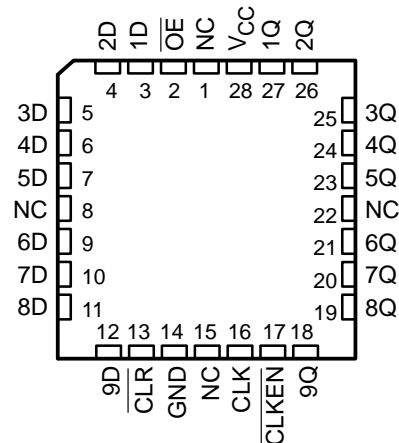
The SN74ABT823 is available in TI's shrink small-outline package (DB), which provides the same I/O pin count and functionality of standard small-outline packages in less than half the printed-circuit-board area.

The SN54ABT823 is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74ABT823 is characterized for operation from -40°C to 85°C .

SN54ABT823 . . . JT OR W PACKAGE
SN74ABT823 . . . DB, DW, OR NT PACKAGE
(TOP VIEW)



SN54ABT823 . . . FK PACKAGE
(TOP VIEW)



NC – No internal connection

EPIC-II^B is a trademark of Texas Instruments Incorporated.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

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SN54ABT823, SN74ABT823

9-BIT BUS-INTERFACE FLIP-FLOPS

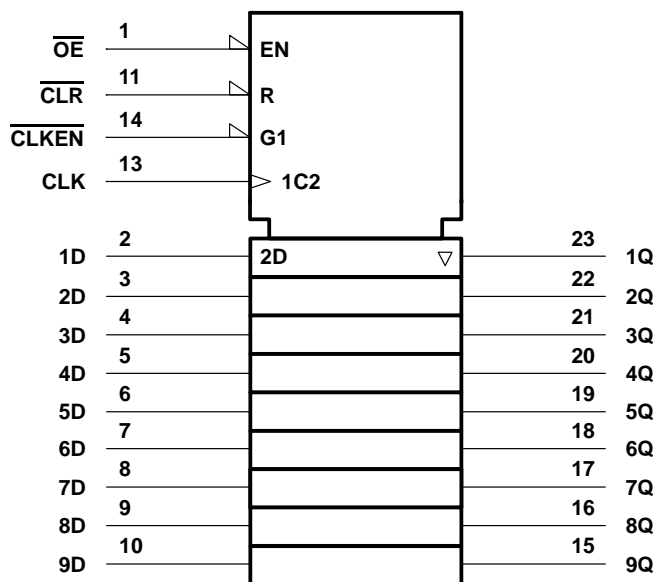
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FUNCTION TABLE
(each flip-flop)

INPUTS					OUTPUT Q
\overline{OE}	\overline{CLR}	\overline{CLKEN}	CLK	D	
L	L	X	X	X	L
L	H	L	\uparrow	H	H
L	H	L	\uparrow	L	L
L	H	H	X	X	Q_0
H	X	X	X	X	Z

logic symbol†

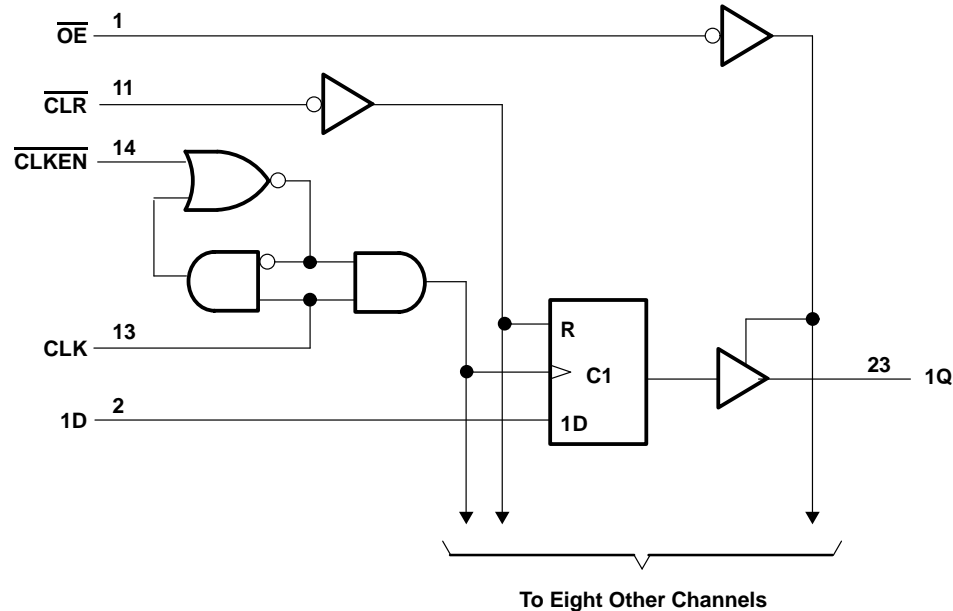


† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for the DB, DW, JT, NT, and W packages.

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logic diagram (positive logic)



Pin numbers shown are for the DB, DW, JT, NT, and W packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC}	–0.5 V to 7 V
Input voltage range, V_I (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high state or power-off state, V_O	–0.5 V to 5.5 V
Current into any output in the low state, I_O : SN54ABT823	96 mA
SN74ABT823	128 mA
Input clamp current, I_{IK} ($V_I < 0$)	–18 mA
Output clamp current, I_{OK} ($V_O < 0$)	–50 mA
Maximum power dissipation at $T_A = 55^\circ\text{C}$ (in still air) (see Note 2): DB package	0.65 W
DW package	1.7 W
NT package	1.3 W
Storage temperature range	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond those indicated in the “recommended operating conditions” section of this specification is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils, except for the NT package, which has a trace length of zero. For more information, refer to the *Package Thermal Considerations* application note in the 1994 *ABT Advanced BiCMOS Technology Data Book*, literature number SCBD002B.

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recommended operating conditions (see Note 3)

		SN54ABT823		SN74ABT823		UNIT
		MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage	4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage	2		2		V
V_{IL}	Low-level input voltage		0.8		0.8	V
V_I	Input voltage	0	V_{CC}	0	V_{CC}	V
I_{OH}	High-level output current		–24		–32	mA
I_{OL}	Low-level output current		48		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate		5		5	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate	200		200		μ s/V
T_A	Operating free-air temperature	–55	125	–40	85	°C

NOTE 3: Unused or floating inputs must be held high or low.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A = 25^\circ\text{C}$			SN54ABT823		SN74ABT823		UNIT
					MIN	MAX	MIN	MAX	
V_{IK}	$V_{CC} = 4.5\text{ V}$, $I_I = -18\text{ mA}$			–1.2		–1.2		–1.2	V
V_{OH}	$V_{CC} = 4.5\text{ V}$, $I_{OH} = -3\text{ mA}$			2.5		2.5		2.5	V
	$V_{CC} = 5\text{ V}$, $I_{OH} = -3\text{ mA}$			3		3		3	
	$V_{CC} = 4.5\text{ V}$	$I_{OH} = -24\text{ mA}$		2		2			
		$I_{OH} = -32\text{ mA}$		2*				2	
V_{OL}	$V_{CC} = 4.5\text{ V}$	$I_{OL} = 48\text{ mA}$				0.55		0.55	V
		$I_{OL} = 64\text{ mA}$				0.55*		0.55	
I_I	$V_{CC} = 5.5\text{ V}$, $V_I = V_{CC}$ or GND			± 1		± 1		± 1	μ A
I_{OZPU}	$V_{CC} = 0$ to 2.1 V , $V_O = 0.5$ to 2.7 V , $\overline{OE} = X$			± 50		± 50		± 50	μ A
I_{OZPD}	$V_{CC} = 2.1\text{ V}$ to 0 , $V_O = 0.5$ to 2.7 V , $\overline{OE} = X$			± 50		± 50		± 50	μ A
I_{OZH}	$V_{CC} = 2.1\text{ V}$ to 5.5 V , $V_O = 2.7\text{ V}$, $\overline{OE} \geq 2\text{ V}$			10^\ddagger		10^\ddagger		10^\ddagger	μ A
I_{OZL}	$V_{CC} = 2.1\text{ V}$ to 5.5 V , $V_O = 0.5\text{ V}$, $\overline{OE} \geq 2\text{ V}$			-10^\ddagger		-10^\ddagger		-10^\ddagger	μ A
I_{off}	$V_{CC} = 0$, V_I or $V_O \leq 4.5\text{ V}$			± 100				± 100	μ A
I_{CEX}	$V_{CC} = 5.5\text{ V}$, $V_O = 5.5\text{ V}$	Outputs high		50		50		50	μ A
I_O^\S	$V_{CC} = 5.5\text{ V}$, $V_O = 2.5\text{ V}$			–50 –140 –180		–50 –180		–50 –180	mA
I_{CC}	$V_{CC} = 5.5\text{ V}$, $V_I = V_{CC}$ or GND $I_O = 0$,	Outputs high		1 250		250		250	μ A
		Outputs low		24 38		38		38	mA
		Outputs disabled		0.5 250		250		250	μ A
ΔI_{CC}^\P	$V_{CC} = 5.5\text{ V}$, One input at 3.4 V , Other inputs at V_{CC} or GND			1.5		1.5		1.5	mA
C_i	$V_I = 2.5\text{ V}$ or 0.5 V			4					pF

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timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

			$V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$		SN54ABT823		SN74ABT823		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
f_{clock}	Clock frequency		0	125	0	125	0	125	MHz
t_w	Pulse duration	$\overline{\text{CLR}}$ low	5.5		5.5		5.5		ns
		CLK high	2.9		2.9		2.9		
		CLK low	3.8		3.8		3.8		
t_{su}	Setup time before CLK \uparrow	$\overline{\text{CLR}}$ inactive	2.5		2.5		2.5		ns
		Data	2.1		2.1		2.1		
		CLKEN high	2		2		2		
		CLKEN low	3.3		3.3		3.3		
t_h	Hold time after CLK \uparrow	Data	1.3		1.3		1.3		ns
		CLKEN high	1		1		1		
		CLKEN low	2		2		2		

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50\text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$			SN54ABT823		SN74ABT823		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
f_{max}			125	200		125		125		MHz
t_{PLH}	CLK	Q	2.1	4.3	5.9	2.1	8.1	2.1	6.8	ns
t_{PHL}			2.2	4.4	6.1	2.2	7	2.2	6.7	
t_{PHL}	$\overline{\text{CLR}}$	Q	2	4.1	6.3	2	7.3	2	7.1	ns
t_{PZH}	$\overline{\text{OE}}$	Q	1	3	4.7 \dagger	1	6.3	1	6 \dagger	ns
t_{PZL}			2.2	4.1	5.6	2.2	6.6	2.2	6.5 \dagger	
t_{PHZ}	$\overline{\text{OE}}$	Q	2.7	4.8	6.5 \dagger	2.7	7.7	2.7	7.5 \dagger	ns
t_{PLZ}			2.8	5	6.4	2.8	7.4	2.8	6.9	

\dagger This data sheet limit may vary among suppliers.

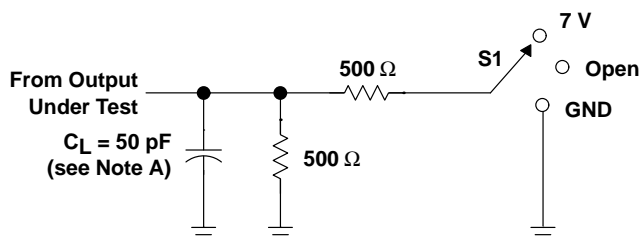
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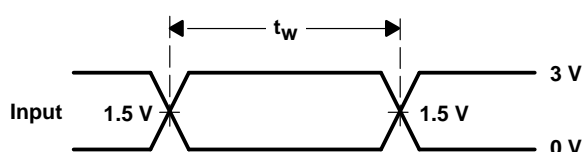
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PARAMETER MEASUREMENT INFORMATION

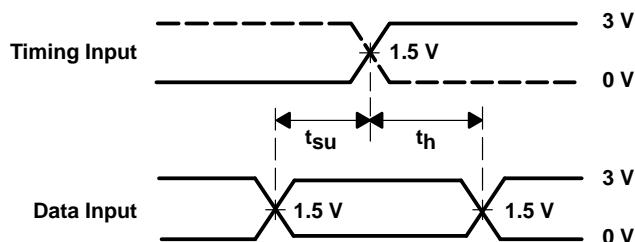


LOAD CIRCUIT FOR OUTPUTS

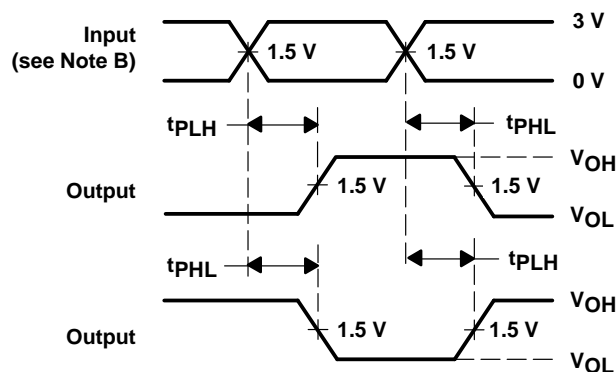
TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	7 V
t_{PHZ}/t_{PZH}	Open



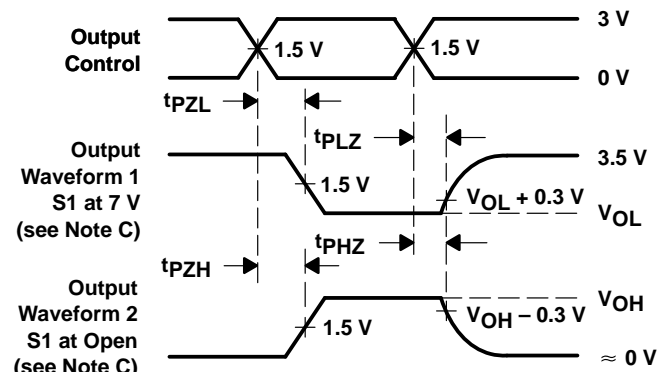
VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

- NOTES: A. C_L includes probe and jig capacitance.
 B. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r \leq 2.5 \text{ ns}$, $t_f \leq 2.5 \text{ ns}$.
 C. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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